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Existence of electron and hole pockets and partial gap opening in correlated semimetal $\text{Ca}_3\text{Ru}_2\text{O}_7$

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The electronic band structure of correlated $\text{Ca}_3\text{Ru}_2\text{O}_7$ featuring an antiferromagnetic as well as a structural transition has been determined theoretically at high temperatures, which has led to the understanding of the remarkable properties of $\text{Ca}_3\text{Ru}_2\text{O}_7$ such as the bulk spin valve effects. However, its band structure and Fermi surface (FS) below the structural transition have not been resolved even though a FS consisting of electron pockets was found experimentally. Here we report magneto electrical transport and thermoelectric measurements with the electric current and temperature gradient directed along a and b axes of an untwined single crystal of $\text{Ca}_3\text{Ru}_2\text{O}_7$ respectively. The thermopower obtained along the two crystal axes were found to show opposite signs at low temperatures, demonstrating the presence of both electron and hole pockets on the FS. In addition, how the FS evolves across $T^* = 30$ K at which a distinct transition from coherent to incoherent behavior occurs was also inferred - the Hall and Nernst coefficient results suggest a temperature and momentum dependent partial gap opening in $\text{Ca}_3\text{Ru}_2\text{O}_7$ below the structural transition, with a possible Lifshitz transition occurring at T^* . The experimental demonstration of a correlated semimetal ground state in $\text{Ca}_3\text{Ru}_2\text{O}_7$ calls for further theoretical studies of this remarkable material.

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Layered ruthenates in the Ruddlesden-Popper series family $(\text{Sr}, \text{Ca})_{n+1}\text{Ru}_n\text{O}_{3n+1}$ ¹ have attracted great attention in condensed matter and materials physics community because they were found to show a wide range of exciting phenomena, including spin-triplet superconductivity in Sr_2RuO_4 ²⁻⁴, band-dependent Mott metal-insulator transition^{5,6} and orbital ordering⁷ in Ca_2RuO_4 , metamagnetism, and correlated effects in $\text{Sr}_3\text{Ru}_2\text{O}_7$ ⁸⁻¹⁰, making them a canonical complex transition metal oxide system for the search of new physical phenomena. The evolution of physics in the Ruddlesden-Popper family $(\text{Sr}, \text{Ca})_{n+1}\text{Ru}_n\text{O}_{3n+1}$ through the reduction of cation radius, marked by the change of the system from the quantum magnet $\text{Sr}_3\text{Ru}_2\text{O}_7$ to antiferromagnetic metal $\text{Ca}_3\text{Ru}_2\text{O}_7$ ¹¹, as well as the increase in the number of perovskite RuO_2 layers that leads to the transition from a band-dependent Mott insulator Ca_2RuO_4 to the metallic $\text{Ca}_3\text{Ru}_2\text{O}_7$ with a k -dependent gap^{12,13}, is particularly interesting.

$\text{Ca}_3\text{Ru}_2\text{O}_7$ was found to show a paramagnetic (PM) metal to antiferromagnetic (AFM) metal transition at $T_N = 56$ K¹⁴. For 48 K $< T < T_N$, the AFM state is characterized by ferromagnetic bilayers stacked antiferromagnetically along the c -axis, with the magnetic moments aligned along the a -axis. As the temperature is lowered below $T_s = 48$ K, the system exhibits a first-order phase transition, characterized by the switching of magnetic

moments from the a - to the b -axis¹⁵ and multiple other changes. Although the orthorhombic crystal symmetry (space group of $\text{Bb2}_1\text{m}$) remains unchanged through the first-order transition at T_s , the structural transition is marked by a clear change in the lattice parameters: the c -axis lattice constant is shortened, while those of the a - and b -axis are enlarged. Such lattice parameter changes are accompanied by the enhanced rotation and tilting of RuO_6 octahedra below T_s ¹⁶, as illustrated in Fig. 1(a,b). Interestingly, the first-order phase transition at T_s is also accompanied by a sharp increase in the in-plane resistivity ρ_{ab} ¹⁷, followed by a negative $d\rho_{ab}/dT$, identified previously as a metal-insulator transition. Additionally, a dramatic bulk spin-valve phenomenon was discovered¹⁸ and understood based on the unusual itinerary magnetic state¹⁹.

Electronic band structures of correlated metals such as $\text{Ca}_3\text{Ru}_2\text{O}_7$ which serves as a useful starting point to understand its physical properties, can be calculated if the correlated effects are dealt with properly and verified experimentally. Even though the band structure calculations of $\text{Ca}_3\text{Ru}_2\text{O}_7$ were attempted²⁰, no results consistent with experimental results have been reported. On the other hand, a tight-binding argument suggests the presence of hole pockets in addition to electron ones²¹. Experimentally, ARPES also revealed the presence of small electron pockets at low temperatures, which will

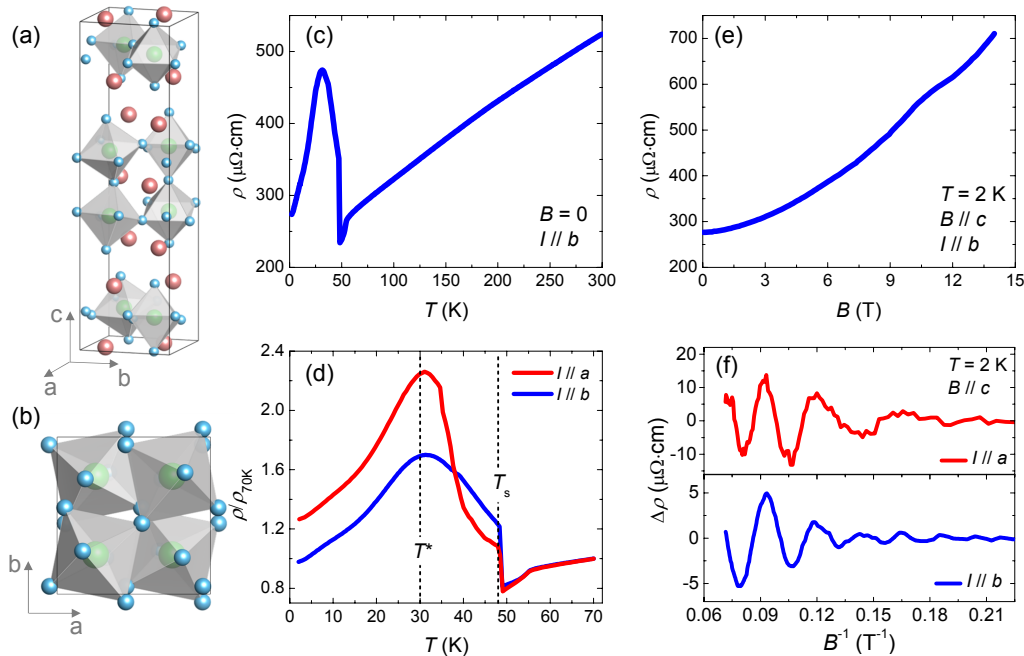


FIG. 1. (a) Crystal structure of $\text{Ca}_3\text{Ru}_2\text{O}_7$. Red, green and blue balls stand for Ca, Ru and Oxygen, respectively. (b) The top view of the unit cell, with Ca cations neglected. (c) Zero-field resistivity of $\text{Ca}_3\text{Ru}_2\text{O}_7$ along the b axis as a function of temperature. (d) Temperature dependence of normalized resistivity along a and b axes. (e) Field dependence of b -axis direction resistivity at 2 K for magnetic field along the c axis. (f) Shubnikov-de Haas oscillations at 2 K along a and b axes with magnetic field along the c axis obtained from $\rho(H)$ by subtracting smooth background.

account for the observed in-plane metallic behavior. Previous quantum oscillations measurements have yielded partly inconsistent results in the presence of multiple frequencies^{21–23}. In addition, $\rho_{ab}(T)$ was found to become metallic below $T^* = 30$ K, raising questions on whether the “insulating” state for $T^* < T < T_s$ is actually metallic possessing a FS and the origin of change from the incoherent to coherent behavior at around T^* . It also raises an interesting question on the nature of this first-order phase transition at T_s to begin with. In this regard, the opening of a density wave at T_s was suggested based on optical spectroscopic studies²⁴. No direct evidence for the presence of a density wave has been found in $\text{Ca}_3\text{Ru}_2\text{O}_7$ however. In this regard, even a momentum dependent gap was indeed observed in ARPES measurements below T_s ²², the FS cannot be determined by either the quantum oscillations or ARPES measurements at such high temperatures. All this calls for alternative methods to determine the FS. Here, using orientation dependent magneto electrical and thermoelectric transport measurements, we find the first experimental evidence for the presence of both electron and hole pockets and partial gap opening.

Single crystals of $\text{Ca}_3\text{Ru}_2\text{O}_7$ were grown by floating zone technique. To probe physics related to the in-plane anisotropy, it is critical to use clean twin-free crystals. For this, we performed systematic screening procedure using X-ray diffraction, Laue diffraction and SQUID

magnetometry to identify clean twin-free crystals. Selected crystals were cut along the a and b axis, respectively, with a rectangular shape. Resistivity, Hall and thermoelectric measurements were performed in a Quantum Design PPMS system with a 14 Tesla magnet. A steady-state technique was used in thermoelectric measurements. The direction of $-\nabla T$ relative to directions in the first Brillouin zone is shown schematically by the arrows in the insets of Fig. 2. This allows perturbation of part of Fermi surfaces with Fermi velocity parallel to $-\nabla T$. For systems with anisotropic electronic states, this method can be a sensitive probe in complementary to well established probes such as Shubnikov-de Haas oscillation and ARPES measurements.

At high temperatures, $\text{Ca}_3\text{Ru}_2\text{O}_7$ was found to feature metallic behavior, as shown in zero-field resistivity data obtained in a sample prepared by a b -axis crystal in Fig. 1(c). A change in slope appeared at T_N , corresponding to the onset of the AFM transition. Upon further cooling, a sharp jump in resistivity was found, along with a negative slope in $\rho(T)$, as seen previously in the in-plane resistivity measurements with an unspecified in-plane current direction¹⁶. At T^* , resistivity values obtained along both a - and b -axis were found to show an incoherent-to-coherent crossover (Fig. 1(d)), well above the temperature at which a similar transition was found in the c -axis resistivity (at $T = 8$ K). Magnetoresistance (MR) at low temperatures was found to show Shubnikov-

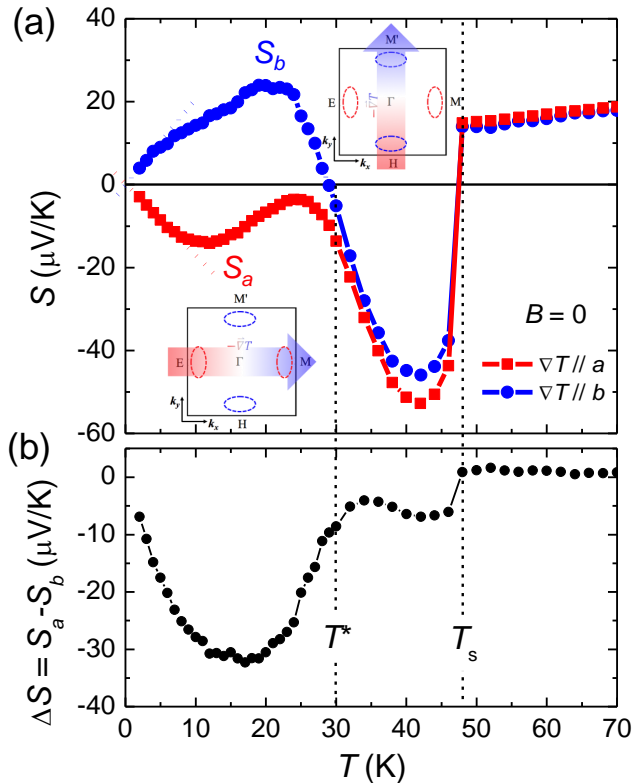


FIG. 2. (a) Zero-field thermopower of $\text{Ca}_3\text{Ru}_2\text{O}_7$ along a and b axes as a function of temperature. Inset schematics show a low-temperature Fermi surface schematic adopted from²², the direction of the thermal gradient in the k space; (b) The temperature dependence of thermopower anisotropy, defined as $\Delta S = S_a - S_b$.

de Haas oscillations (SdHOs), as seen in the $\rho(H)$ curve in Fig. 1(e). The oscillatory part in $\rho(H)$, obtained by subtracting a smooth background, is plotted in Fig. 1(f). The periodicity in the $\Delta\rho(B^{-1})$ for both a and b -axis resistivity gives a frequency in SdHOs of ~ 41 T, suggesting rather tiny FS pockets, $\sim 1\%$ BZ, a value consistent with those found previously^{21,23,25}.

Thermopower data measured with the temperature gradient along a and b axes, denoted as S_a and S_b , respectively, are shown in Fig. 2. It is seen that both S_a and S_b are positive and nearly identical at high temperatures. With the decreasing temperature, the thermopower was found to decrease, but no signature was found at the magnetic transition around T_N . At T_s , a sharp drop was found in both S_a and S_b , with the difference between the two becoming significant. At around $T^* = 30$ K, S_b changed sign to positive while S_a remains negative. The magnitudes of both S_a and S_b were seen to decrease in the low-temperature limit, as required for an entropy current.

Consider now the implication of the thermopower data. Neglecting correlation effects, thermopower of electrons

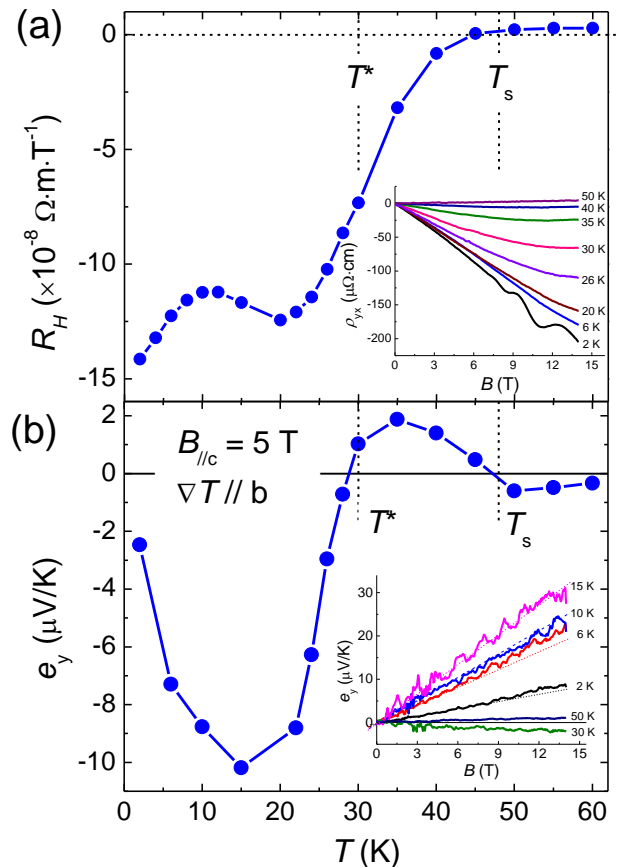


FIG. 3. (a) Temperature dependence of Hall coefficient in $\text{Ca}_3\text{Ru}_2\text{O}_7$. Inset shows the field dependence of Hall resistivity at various temperatures; (b) Temperature dependence of Nernst signal e_y in $\text{Ca}_3\text{Ru}_2\text{O}_7$. Inset shows the field dependence of the Nernst signal. Thermal gradient is along the b axis.

can be expressed in terms of conductivity^{26,27},

$$S = \frac{\alpha_{xx}}{\sigma_{xx}} = -\frac{\pi^2 k_B^2 T}{3|e|} \left. \frac{\partial \ln \sigma}{\partial E} \right|_{E_F} \quad (1)$$

$$= -\frac{\pi^2 k_B^2 T}{3|e|} \left[\frac{1}{A} \frac{\partial A}{\partial E} + \frac{1}{l} \frac{\partial l}{\partial E} \right] \Big|_{E_F}$$

where σ denotes the conductivity, α the Peltier conductivity, A the FS area, and l the carrier mean free path. One can see that thermopower is therefore a measure of the variation in conductivity with respect to chemical potential. In general, the second term in the square brackets in eq.1 is much smaller than the first term, therefore the sign of thermopower is related directly to the carrier type of the dominating band.

As discussed above, earlier works on quantum oscillation, ARPES and band structure calculation has set up clear boundary condition: tiny FS consisting possible features around M and M' points (electron- and hole-like pockets)^{21,22}. In our measurement, the thermal gradient $-\nabla T$ was directed towards the Γ -M and Γ -M' direction

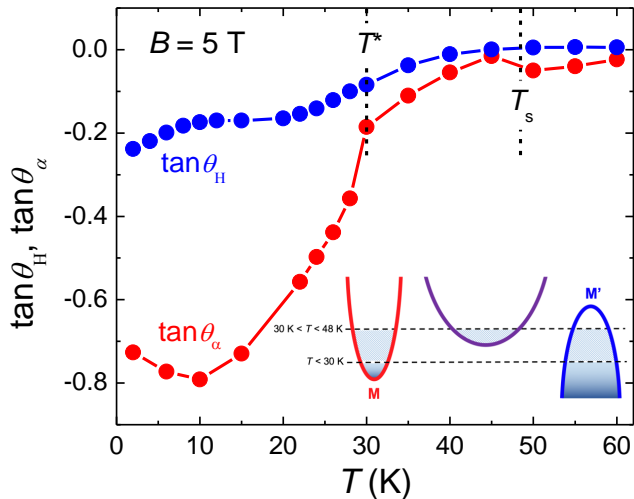


FIG. 4. The temperature dependence of thermal Hall $\tan\theta_\alpha$ and Hall angle $\tan\theta_H$ at 5 T. Inset: a schematic showing a possible Lifshitz transition driven by the shift of chemical potential. Below the structural transition, the band structure of $\text{Ca}_3\text{Ru}_2\text{O}_7$ consists of an electron and hole band at M and M' point, and another electron-like band. The chemical potential decreases with lowering temperature, and misses the large electron-like band when cooling below T^* .

in the k space for S_a and S_b , respectively. The negative S_a and positive S_b seen at low temperatures therefore indicate the existence of a dominating electron and hole bands in their respective directions: the first evidence supporting the presence of both electron and hole pockets in $\text{Ca}_3\text{Ru}_2\text{O}_7$. In a one-band nearly-free-electron approximation²⁸, $S = \frac{\pi^2 k_B}{2e} \frac{T}{T_F}$, the slope of $S(T)$ at low-temperature provides an estimate of the Fermi temperature, leading to $T_F^+ = 350$ K for the hole pocket and for the electron pocket, $T_F^- = 425$ K. The rather low Fermi temperatures are expected for a low carrier density system. On the other hand, it is also important to note that in the presence of subtle FS structures, for instance, a van Hove singularity near the FS²⁹, or complex FS curvatures³⁰, the sign of thermopower cannot be linked to the type of carrier directly. However, these special cases do not seem to occur in our system according to earlier ARPES and band structure calculation as discussed above.

Values of $\Delta S = S_a - S_b$, a quantitative measure of the thermopower anisotropy, plotted in Fig. 2(b), suggests strongly the presence of two regimes below $T_s = 48$ K. The sharp change also indicates that additional change occurs at around 30 K, which cannot be accounted for by the gapped bands at 48 K as described in an earlier thermopower measured with an arbitrary in-plane direction³¹. To understand the nature of the electronic state in these two regimes, as well as that of the incoherent-coherent crossover found at $T^* = 30$ K, we investigated further the Hall and Nernst effect in

$\text{Ca}_3\text{Ru}_2\text{O}_7$. The Hall resistivity ρ_H in the inset of Fig. 3(a) is seen to depend on the field linearly at low fields with nonlinearity seen at high fields, which is attributed to multiband effects. The Hall coefficient R_H shown in Fig. 3(a) reveals a sign change at the first-order phase transition at T_s , and nonmonotonic temperature dependence at lower temperatures. The sharp increase in the magnitude of R_H suggests a rapid growth in l_e/l_h , and thus a significant reduction in scattering in the electron-like bands³⁰. It is worth to note that similar behavior has been found in several two-dimensional CDW systems featuring saddle points on the FS³². Whether this applies to $\text{Ca}_3\text{Ru}_2\text{O}_7$ is yet to be verified.

The Nernst signal $e_y = E_y/\nabla T$ measures the transverse electric field E_y generated by a longitudinal temperature gradient $-\nabla T$ in the presence of magnetic field. Here e_y was measured with $-\nabla T$ along b axis and was found to depend on the field linearly at low fields. Nonlinearity is seen at high fields (inset in Fig. 3(b)). In addition, the temperature dependence of e_y shown in Fig. 3(b) features a sign change at T_s and slightly below T^* . A drastic enhancement in its magnitude was found below T^* , reaching a value as large as $10 \mu\text{V}/\text{K}$ at 15 K. A large e_y can arise from several possible sources^{28,33}. In the two-band picture

$$e_y = S \left(\frac{\alpha_{xy}^+ + \alpha_{xy}^-}{\alpha_{xx}^+ + \alpha_{xx}^-} - \frac{\sigma_{xy}^+ + \sigma_{xy}^-}{\sigma_{xx}^+ + \sigma_{xx}^-} \right). \quad (2)$$

where α is the Peltier conductivity tensor with the sign of carriers denoted by the superscript, “+” or “-” for the holes and the electrons, respectively. We note that from the Hall coefficient $R_H(T)$, the system is compensated at around T_s , i.e., $\sigma_{xy}^+ = -\sigma_{xy}^-$, leading to a vanished second term in eq. 2. Therefore, a sizable change in e_y around T_s is expected. e_y was also found to change sign at T_s , indicating that the first term in e_y is comparable to the second term around this temperature. For the same reason, e_y remains relatively small. Below T^* , R_H becomes increasingly negative, while e_y is negative and large in magnitude. Therefore the sharp decrease in e_y must come from a strong reduction in the first term, i.e., the off-diagonal Peltier coefficient term, which points to a change in scattering rate for $T < T^*$. This change in the scattering rate is further demonstrated in Fig. 4. Here we compare the temperature dependence of Hall angle $\tan\theta_H = \sigma_{xy}/\sigma_{xx}$ and the Peltier angle $\tan\theta_\alpha = \alpha_{xy}/\alpha_{xx}$. The former corresponds to the carrier mobility therefore probes the scattering time while the latter is sensitive to the energy dependence of the scattering time³³. It is seen that $\tan\theta_H$ features an increase in its magnitude below T_s but no anomaly around T^* . On the other hand, the Peltier angle is seen to show a rapid increase at T^* . The large Peltier angle, nearly four times bigger than the Hall angle, suggests a significant change in the energy dependence of the conductance for $T < T^*$.

The above measurements would suggest a momentum dependent gap opening below T_s and the electronic state

of $\text{Ca}_3\text{Ru}_2\text{O}_7$ experiences a significant change at around T^* . For $T^* < T < T_s$, limited part of the FS is gapped out, leaving thermopower taken with $-\nabla T$ along both Γ - M and Γ - M' directions dominated by an electron-like band. As a result, both S_a and S_b are negative and the anisotropy ΔS is small. Below T^* , however, most of the electron-like band on the FS is gapped out, but the electron and hole pockets near M and M' points survive. Furthermore, the temperature dependent gap opening occurs gradually over a large temperature range as the temperature is lowered below T_s , which explains the absence of a clear signature at T^* in specific heat data^{17,34}.

It is likely that the density wave formation is responsible for the momentum dependent gap opening, provided that the nesting condition for the density wave varies with the temperature. This will result in a temperature dependent gap opening. The existing ARPES data appears to support this scenario. In this regard, a small jump in the k -dependent gap was found around T^* in earlier ARPES data (see Fig. 4(c) in Ref.²²), which not only supports the temperature-dependent nesting condition picture but also suggests a Lifshitz transition driven by a shift in the chemical potential as the temperature is lowered, as depicted in the inset of Fig. 4. In this picture, the change in the nesting condition is abrupt at T^* . Lifshitz transition describes the change of Fermi surface topology without breaking any symmetry of the system. The continuous change of an order parameters, as found in traditional phase transitions, no longer exist. Instead, the topological invariants dictate the transition. Incidentally, an appreciable change in chemical potential was indeed found to exist in several semimetals^{35,36}. It is known that a Lifshitz transition will affect the mate-

rial property significantly due to the reconstructed FS, especially in materials with magnetic or charge instabilities. For example, the nesting condition was found to change significantly at the Lifshitz transition in pnictide superconductors³⁷. A similar situation may be encountered in $\text{Ca}_3\text{Ru}_2\text{O}_7$.

In summary, we provide the first experimental evidence for the existence of both electron and hole pockets in $\text{Ca}_3\text{Ru}_2\text{O}_7$ at low temperatures through the measurement of anisotropic thermopower. Furthermore, from the measurement of Hall and Nernst coefficient, we found evidence for a partial gap opening in an extended temperature range below T_s . These findings help in resolving the standing issue on the low-temperature Fermi surface configuration and provide new insight for further understanding of the intricate behavior of $\text{Ca}_3\text{Ru}_2\text{O}_7$ at around T^* .

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